December 2013

74LCX125 — Low Voltage Quad Buffer with 5V Tolerant Inputs and Outputs



74LCX125 Low Voltage Quad Buffer with 5V Tolerant **Inputs and Outputs**

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0ns t_{PD} max. (V_{CC} = 3.3V), 10µA I_{CC} max.
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal⁽¹⁾
- ± 24 mA output drive (V_{CC} = 3.0V)
- Implements proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds JEDEC 78 conditions
- ESD performance:
 - Human body model > 2000V
 - Machine model > 100V
- Leadless DQFN package

Note:

1. To ensure the high-impedance state during power up or down, \overline{OE} should be tied to V_{CC} through a pull-up resistor: the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Information

Package **Order Number** Number Package Description 74LCX125M M14A 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow 74LCX125SJ 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide M14D 74LCX125BQX⁽²⁾ 14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MLP14A MO-241, 2.5 x 3.0mm 74LCX125MTC 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm MTC14 Wide

Note:

2. DQFN package available in Tape and Reel only.

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

General Description

The LCX125 contains four independent non-inverting buffers with 3-STATE outputs. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX125 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

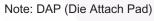
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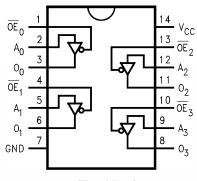


(Top Through View)

Pin Description Pin Names

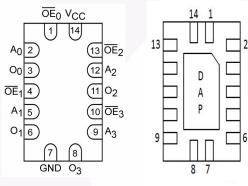
Pin Assignments for SOIC, SOP, and TSSOP

Connection Diagrams



(Top View)

Pad Assignments for DQFN



Inputs

Outputs

No Connect

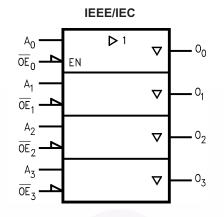
(Bottom View)

Description

Output Enable Inputs

2

Logic Symbol



Truth Table

Inp	Output			
OEn	A _n	O _n		
L	L	L		
L	Н	Н		
Н	Х	Z		

H = HIGH Voltage Level

L = LOW Voltage Level

Z = High Impedance

X = Immaterial

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
VI	DC Input Voltage	-0.5V to +7.0V
Vo	DC Output Voltage,	
	Output in 3-STATE	-0.5V to +7.0V
	Output in HIGH or LOW State ⁽³⁾	-0.5V to V _{CC} + 0.5V
I _{IK}	DC Input Diode Current, V _I < GND	–50mA
I _{OK}	DC Output Diode Current	
	V _O < GND	–50mA
	V _O > V _{CC}	+50mA
Ι _Ο	DC Output Source/Sink Current	±50mA
I _{CC}	DC Supply Current per Supply Pin	±100mA
I _{GND}	DC Ground Current per Ground Pin	±100mA
T _{STG}	Storage Temperature	–65°C to +150°C

Note:

3. I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions⁽⁴⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage			
	Operating	2.0	3.6	V
	Data Retention	1.5	3.6	
VI	Input Voltage	0	5.5	V
Vo	Output Voltage			1
	HIGH or LOW State		V _{CC}	V
	3-STATE	0	5.5	
I _{OH} / I _{OL}	Output Current			
	$V_{CC} = 3.0V - 3.6V$		±24	mA
	V _{CC} = 2.7V–3.0V		±12	
	V _{CC} = 2.3V–2.7V		±8	
T _A	Free-Air Operating Temperature	-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

Note:

4. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

				T _A = -40°C to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min.	Max.	Units
V _{IH}	HIGH Level Input Voltage	2.3–2.7		1.7		V
		2.7–3.6		2.0		
V _{IL}	LOW Level Input Voltage	2.3–2.7			0.7	V
		2.7–3.6			0.8	
V _{OH}	HIGH Level Output Voltage	2.3–3.6	$I_{OH} = -100 \mu A$	V _{CC} – 0.2		V
		2.3	$I_{OH} = -8mA$	1.8]
		2.7	$I_{OH} = -12mA$	2.2]
		3.0	$I_{OH} = -18mA$	2.4]
			$I_{OH} = -24mA$	2.2]
V _{OL}	LOW Level Output Voltage	2.3–3.6	$I_{OL} = 100 \mu A$		0.2	V
		2.3	I _{OL} = 8mA		0.6]
		2.7	$I_{OL} = 12mA$		0.4	
		3.0	$I_{OL} = 16 \text{mA}$		0.4	
			$I_{OL} = 24 \text{mA}$		0.55	
Ц	Input Leakage Current	2.3–3.6	$0 \le V_I \le 5.5V$		±5.0	μA
I _{OZ}	3-STATE Output Leakage	2.3–3.6	$\begin{array}{l} 0 \leq V_O \leq 5.5V, \\ V_I = V_{IH} \text{ or } V_{IL} \end{array}$		±5.0	μA
I _{OFF}	Power-Off Leakage Current	0	$V_{\rm I}$ or $V_{\rm O} = 5.5 V$		10	μA
I _{CC}	Quiescent Supply Current	2.3–3.6	$V_{I} = V_{CC}$ or GND		10	μA
			$3.6V \le V_I, V_O \le 5.5V^{(5)}$		±10	
ΔI_{CC}	Increase in I _{CC} per Input	2.3–3.6	$V_{\rm IH} = V_{\rm CC} - 0.6V$		500	μA

Note:

5. Outputs disabled or 3-STATE only.

AC Electrical Characteristics

		$T_A = -40^{\circ}$ C to +85°C, $R_L = 500\Omega$						
		$V_{CC} = 3.3V \pm 0.3V,$ $C_{L} = 50 \text{ pF}$		V _{CC} = 2.7V, C _L = 50 pF		$\label{eq:V_CC} \begin{split} V_{CC} &= 2.5V \pm 0.2V, \\ C_L &= 30 \ \text{pF} \end{split}$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PHL} , t _{PLH}	Propagation Delay	1.5	6.0	1.5	6.5	1.5	7.2	ns
t _{PZL} , t _{PZH}	Output Enable Time	1.5	7.0	1.5	8.0	1.5	9.1	ns
t _{PLZ} , t _{PHZ}	Output Disable Time	1.5	6.0	1.5	7.0	1.5	7.2	ns
t _{OSHL} , t _{OSLH}	Output to Output Skew ⁽⁶⁾		1.0					ns

Note:

6. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

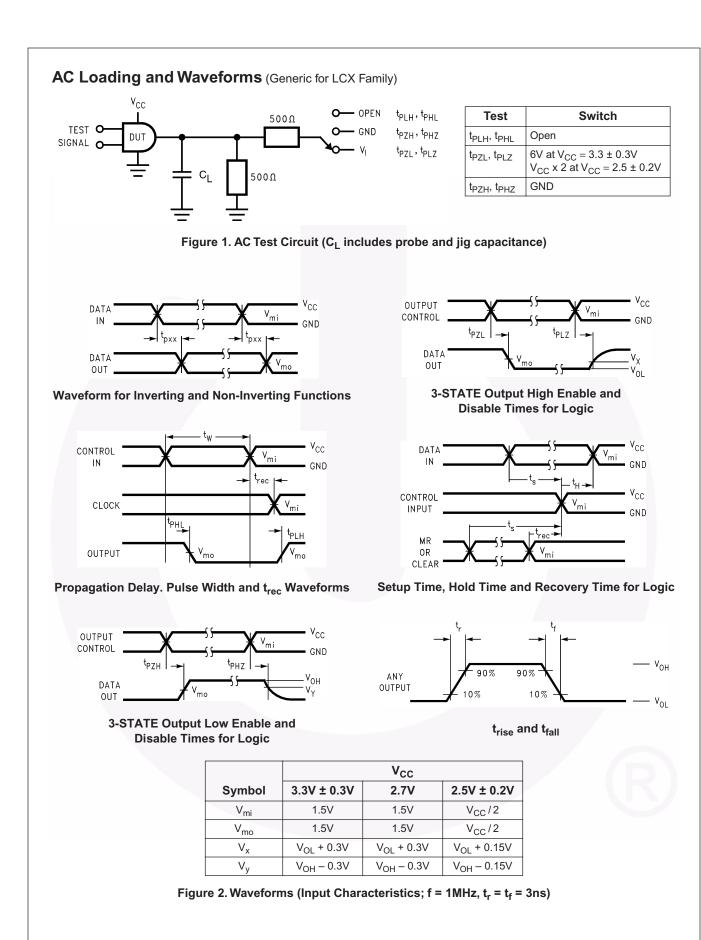
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Dynamic Switching Characteristics

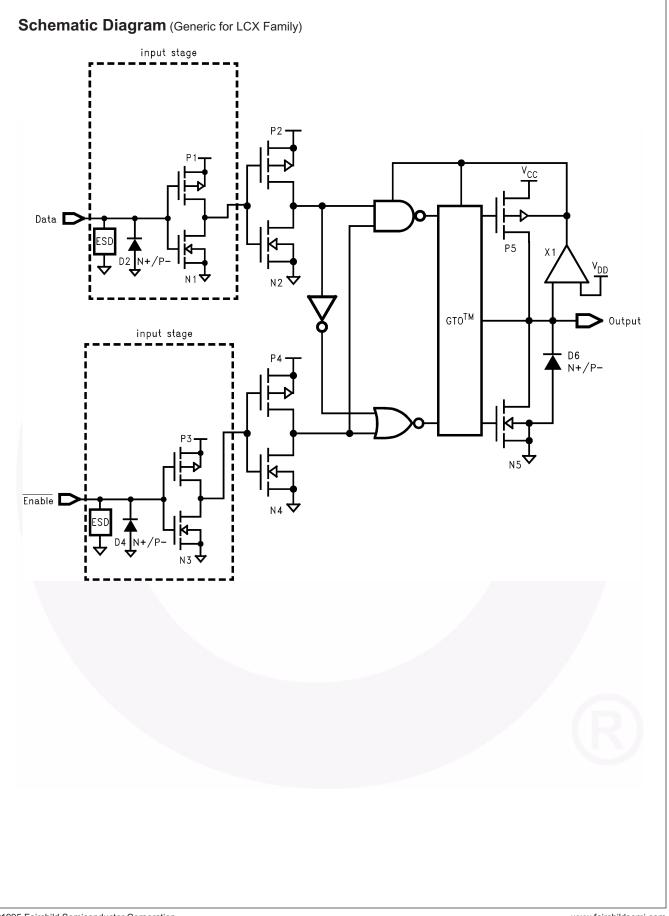
				$T_A = 25^{\circ}C$	
Symbol	Parameter	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V$	0.8	V
		2.5	$C_L = 30 pF$, $V_{IH} = 2.5 V$, $V_{IL} = 0 V$	0.6	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V$	-0.8	V
		2.5	$C_{L} = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V$	-0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7.0	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3 V$, $V_I = 0 V$ or V_{CC}	8.0	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10MHz	25.0	pF



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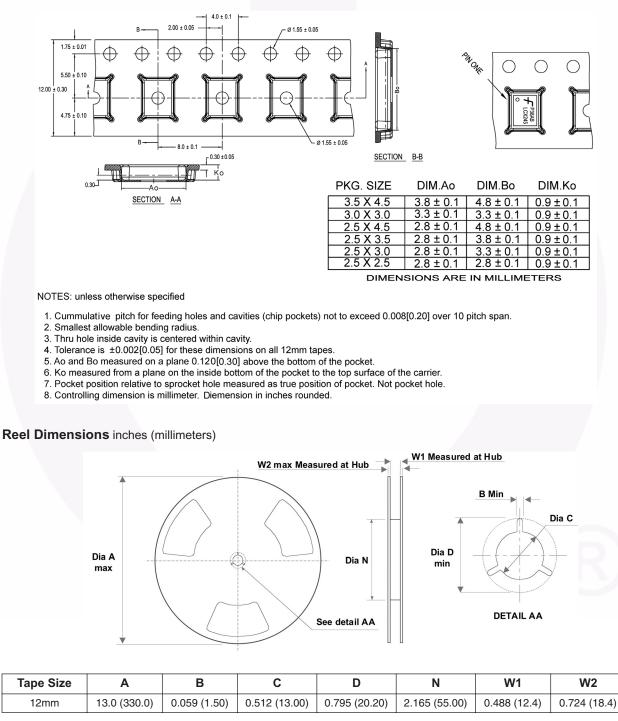
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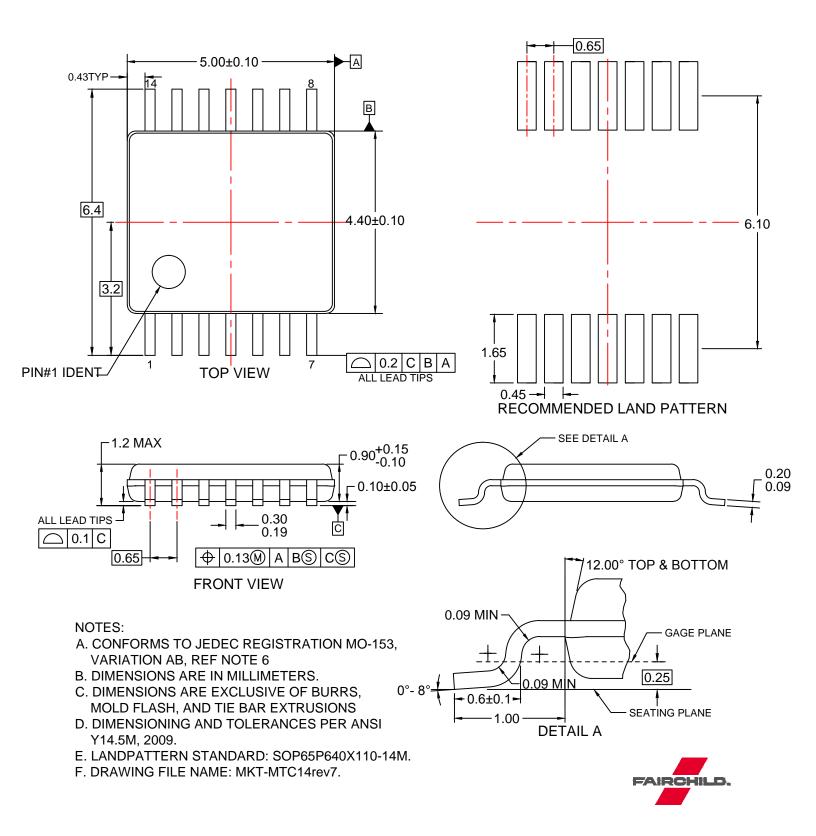
Tape and Reel Specification

Tape Format for DQFN

Package Designator	Tape Section	Number of Cavities	Cavity Status	Cover Tape Status	
BQX	Leader (Start End)	125 (Тур.)	Empty	Sealed	
	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Тур.)	Empty	Sealed	

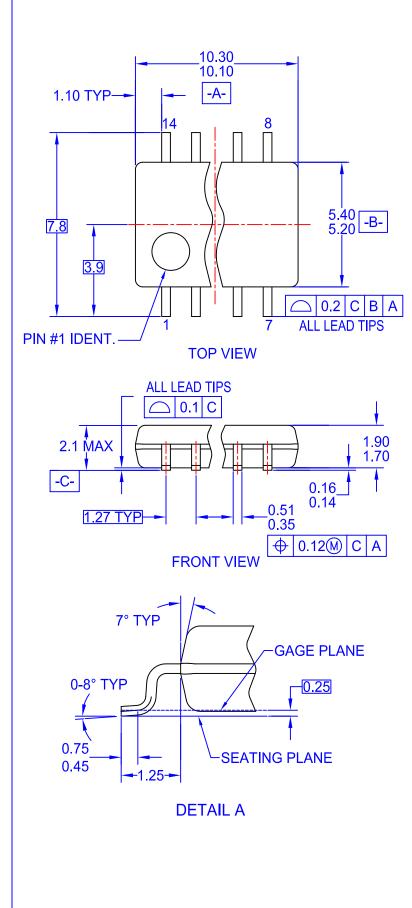
Tape Dimensions inches (millimeters)

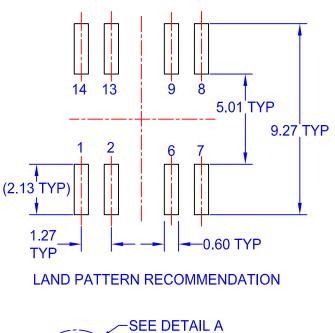


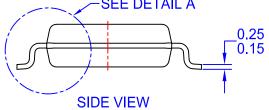


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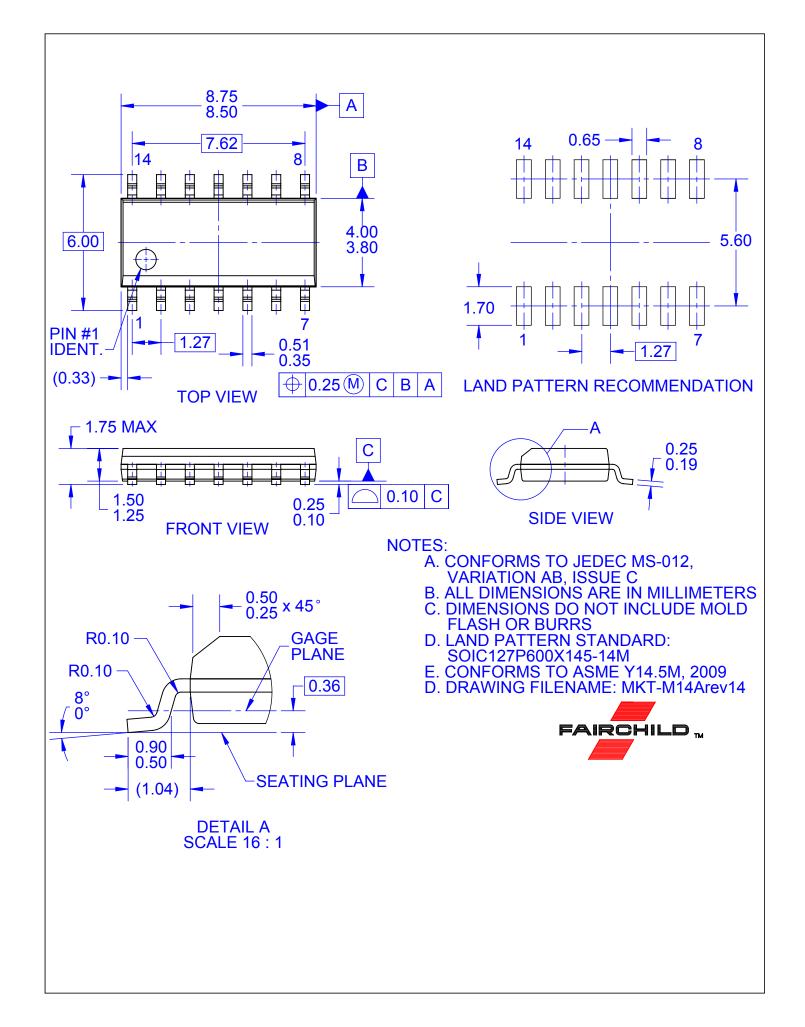


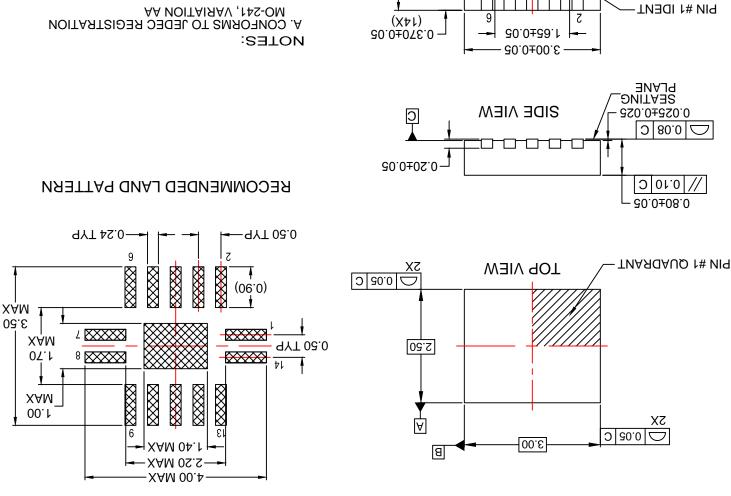


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BOTTOM VIEW

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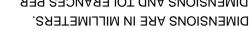
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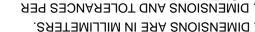
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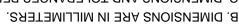
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